

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network

resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SOT-23 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
- Reduces Board Space and Component Count
- The SOT-23 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
- Available in 8 mm embossed tape and reel. Use the Device Number to order the 7 inch/3000 unit reel. Replace “T1” with “T3” in the Device Number to order the 13 inch/10,000 unit reel.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

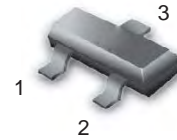
MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	Vdc
Collector-Emitter Voltage	V_{CEO}	50	Vdc
Collector Current	I_C	100	mAdc
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ (Note 1.) Derate above 25°C	P_D	246 1.5	mW $^\circ\text{C/W}$

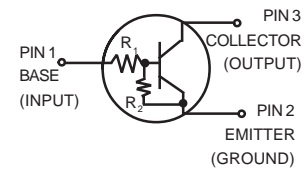
DEVICE MARKING AND RESISTOR VALUES

Device	Marking	R1(K)	R2(K)	$V_{IN}(V)$
MUN2211LT1G	A8A	10	10	-10~+40
MUN2212LT1G	A8B	22	22	-10~+40
MUN2213LT1G	A8C	47	47	-10~+40
MUN2214LT1G	A8D	10	47	-6~+40
MUN2215LT1G	A8E	10	∞	-6~+40
MUN2216LT1G	A8F	4.7	∞	-6~+30
MUN2230LT1G	A8G	1.0	1.0	-10~+10
MUN2231LT1G	A8H	2.2	2.2	-10~+12
MUN2232LT1G	A8J	4.7	4.7	-10~+30
MUN2233LT1G	A8K	4.7	47	-5~+30
MUN2234LT1G	A8L	22	47	-8~+40
MUN2235LT1G	A8M	2.2	47	-6~+12
MUN2236LT1G	A8N	100	100	-10~+40
MUN2237LT1G	A8P	47	22	-10~+40
MUN2238LT1G	A8R	2.2	∞	-6~+12
MUN2240LT1G	A8T	47	∞	-6~+40
MUN2241LT1G	A8U	100	∞	-6~+40

1. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.



SOT-23 (TO-236AB)



We declare that the material of product compliance with RoHS requirements.

Ordering Information

Device	Package	Shipping
MUN2211LT1G	SOT23	3000/Tape&Reel
MUN2211LT3G	SOT23	10000/Tape&Reel

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Resistance – Junction-to-Ambient (Note 1.)	$R_{\theta JA}$	508	°C/W
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	°C
Maximum Temperature for Soldering Purposes, Time in Solder Bath	T_L	260 10	°C Sec

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector-Base Cutoff Current ($V_{CB} = 50\text{ V}, I_E = 0$)	I_{CBO}	–	–	100	nAdc
Collector-Emitter Cutoff Current ($V_{CE} = 50\text{ V}, I_B = 0$)	I_{CEO}	–	–	500	nAdc
Emitter-Base Cutoff Current ($V_{EB} = 6.0\text{ V}, I_C = 0$)	I_{EBO}	–	–	0.5	mAdc
MUN2211LT1G		–	–	0.2	
MUN2212LT1G		–	–	0.1	
MUN2213LT1G		–	–	0.2	
MUN2214LT1G		–	–	0.9	
MUN2215LT1G		–	–	1.9	
MUN2216LT1G		–	–	4.3	
MUN2230LT1G		–	–	2.3	
MUN2231LT1G		–	–	1.5	
MUN2232LT1G		–	–	0.18	
MUN2233LT1G		–	–	0.13	
MUN2234LT1G		–	–	0.2	
MUN2235LT1G		–	–	0.05	
MUN2236LT1G		–	–	0.13	
MUN2237LT1G		–	–	4.0	
MUN2238LT1G		–	–	0.2	
MUN2240LT1G		–	–	0.1	
MUN2241LT1G		–	–		
Collector-Base Breakdown Voltage ($I_C = 10\ \mu\text{A}, I_E = 0$)	$V_{(BR)CBO}$	50	–	–	Vdc
Collector-Emitter Breakdown Voltage (Note 2.), ($I_C = 2.0\text{ mA}, I_B = 0$)	$V_{(BR)CEO}$	50	–	–	Vdc

ON CHARACTERISTICS (Note 2.)

DC Current Gain ($V_{CE} = 10\text{ V}, I_C = 5.0\text{ mA}$)	h_{FE}	35	60	–	
MUN2211LT1G		60	100	–	
MUN2212LT1G		80	140	–	
MUN2213LT1G		80	140	–	
MUN2214LT1G		160	350	–	
MUN2215LT1G		160	350	–	
MUN2216LT1G		3.0	5.0	–	
MUN2230LT1G		8.0	15	–	
MUN2231LT1G		15	30	–	
MUN2232LT1G		80	200	–	
MUN2233LT1G		80	150	–	
MUN2234LT1G		80	140	–	
MUN2235LT1G		80	150	–	
MUN2236LT1G		80	140	–	
MUN2237LT1G		160	350	–	
MUN2238LT1G		160	350	–	
MUN2240LT1G		160	350	–	
MUN2241LT1G		160	350	–	
Collector-Emitter Saturation Voltage ($I_C = 10\text{ mA}, I_B = 0.3\text{ mA}$) ($I_C = 10\text{ mA}, I_B = 5\text{ mA}$) LMUN2230LT1G/LMUN2231LT1G LMUN2237LT1G ($I_C = 10\text{ mA}, I_B = 1\text{ mA}$) LMUN2215LT1G/LMUN2216LT1G LMUN2232LT1G/LMUN2233LT1G/LMUN2234LT1G/ LMUN2235LT1G/LMUN2238LT1G/LMUN2240LT1G	$V_{CE(sat)}$	–	–	0.25	Vdc

2. Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS (Note 3.)					
Output Voltage (on) ($V_{CC} = 5.0\text{ V}$, $V_B = 2.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$)	V_{OL}	–	–	0.2	Vdc
MUN2211LT1G		–	–	0.2	
MUN2212LT1G		–	–	0.2	
MUN2214LT1G		–	–	0.2	
MUN2215LT1G		–	–	0.2	
MUN2216LT1G		–	–	0.2	
MUN2230LT1G		–	–	0.2	
MUN2231LT1G		–	–	0.2	
MUN2232LT1G		–	–	0.2	
MUN2233LT1G		–	–	0.2	
MUN2234LT1G		–	–	0.2	
MUN2235LT1G		–	–	0.2	
MUN2238LT1G		–	–	0.2	
($V_{CC} = 5.0\text{ V}$, $V_B = 5.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$) MUN2236LT1G		–	–	0.2	
($V_{CC} = 5.0\text{ V}$, $V_B = 4.0\text{ V}$, $R_L = 1.0\text{ k}\Omega$) MUN2237LT1G		–	–	0.2	
($V_{CC} = 5.0\text{ V}$, $V_B = 3.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$) MUN2213LT1G		–	–	0.2	
MUN2240LT1G		–	–	0.2	
($V_{CC} = 5.0\text{ V}$, $V_B = 5.0\text{ V}$, $R_L = 1.0\text{ k}\Omega$) MUN2241LT1G		–	–	0.2	
Output Voltage (off) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.050\text{ V}$, $R_L = 1.0\text{ k}\Omega$) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.25\text{ V}$, $R_L = 1.0\text{ k}\Omega$)	V_{OH}	4.9	–	–	Vdc
MUN2230LT1G					
MUN2215LT1G					
MUN2216LT1G					
MUN2233LT1G					
MUN2238LT1G					
MUN2236LT1G					
MUN2237LT1G					
MUN2240LT1G					
Input Resistor	R_1	7.0	10	13	$\text{k}\Omega$
MUN2211LT1G		15.4	22	28.6	
MUN2212LT1G		32.9	47	61.1	
MUN2213LT1G		7.0	10	13	
MUN2214LT1G		7.0	10	13	
MUN2215LT1G		3.3	4.7	6.1	
MUN2216LT1G		0.7	1.0	1.3	
MUN2230LT1G		1.5	2.2	2.9	
MUN2231LT1G		3.3	4.7	6.1	
MUN2232LT1G		3.3	4.7	6.1	
MUN2233LT1G		15.4	22	28.6	
MUN2234LT1G		1.54	2.2	2.86	
MUN2235LT1G		1.54	2.2	2.88	
MUN2238LT1G		70	100	130	
MUN2241LT1G		70	100	130	
MUN2236LT1G		32.9	47	61.1	
MUN2237LT1G		32.9	47	61.1	
MUN2240LT1G					
Resistor Ratio	R_1/R_2	0.8	1.0	1.2	
MUN2211LT1G/MUN2212LT1G/MUN2213LT1G		0.17	0.21	0.25	
MUN2214LT1G		–	–	–	
MUN2215LT1G/MUN2216LT1G/MUN2238LT1G		–	–	–	
MUN2241LT1G/MUN2240LT1G/MUN2230LT1G/		–	–	–	
MUN2231LT1G/MUN2232LT1G		0.8	1.0	1.2	
MUN2236LT1G		0.8	1.0	1.2	
MUN2237LT1G		1.7	2.15	2.6	
MUN2233LT1G		0.055	0.1	0.185	
MUN2234LT1G		0.38	0.47	0.56	
MUN2235LT1G		0.038	0.047	0.056	

3. Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%.

TYPICAL ELECTRICAL CHARACTERISTICS
MUN2211LT1G

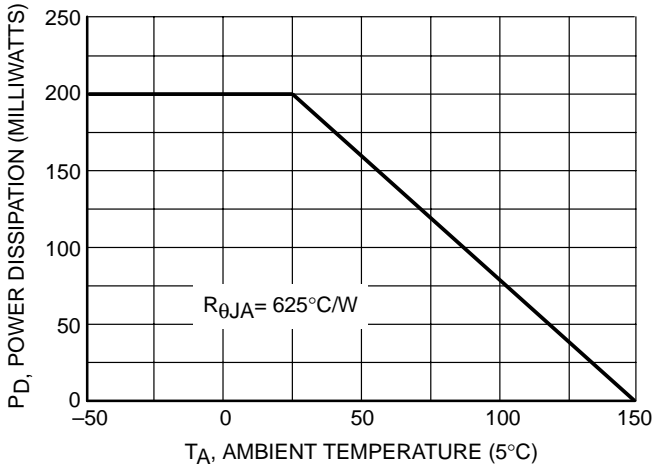


Figure 1. Derating Curve

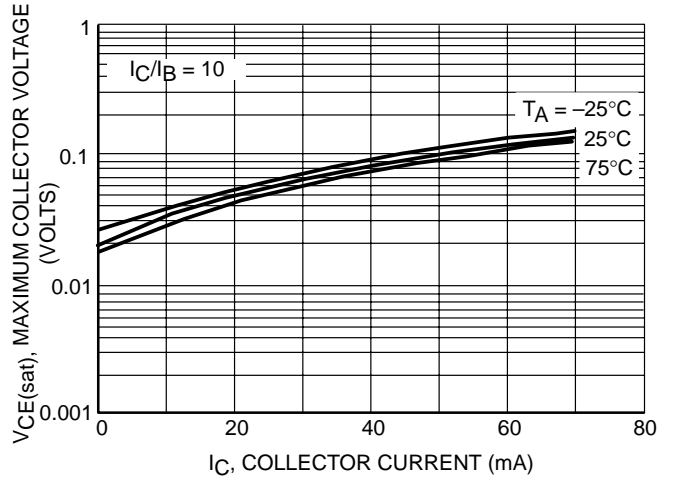


Figure 2. $V_{CE(sat)}$ vs. I_C

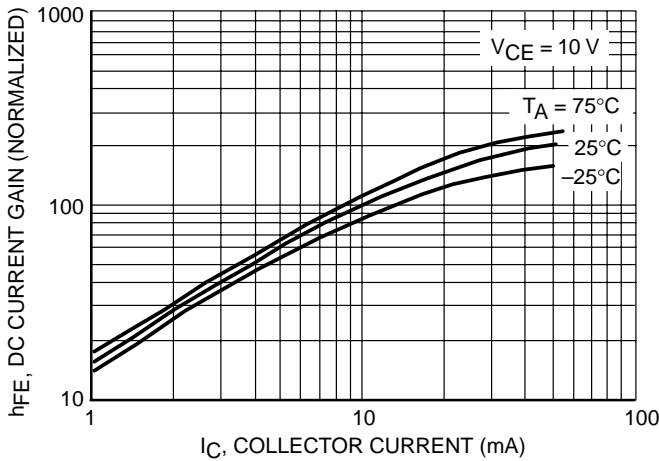


Figure 3. DC Current Gain

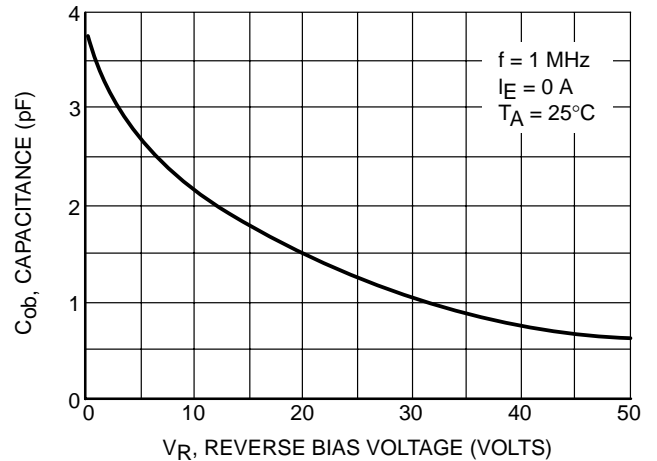


Figure 4. Output Capacitance

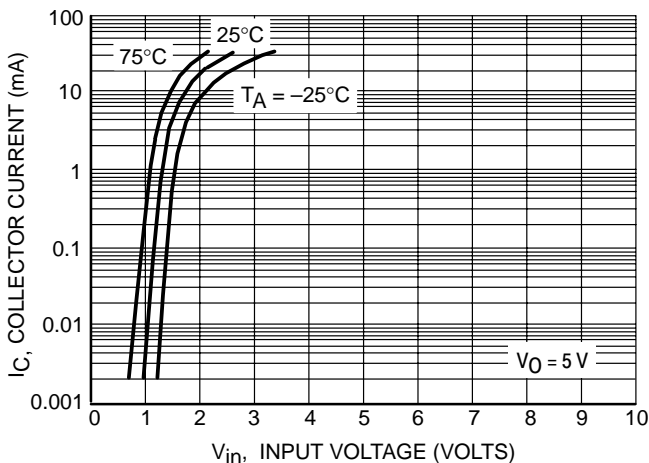


Figure 5. Output Current vs. Input Voltage

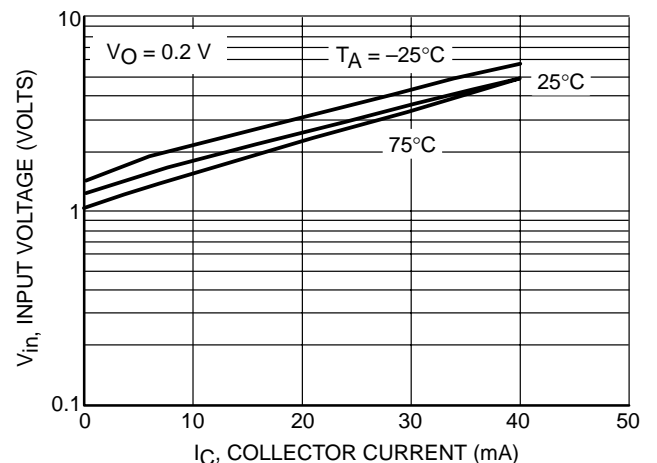


Figure 6. Input Voltage vs. Output Current

**TYPICAL ELECTRICAL CHARACTERISTICS
 MUN2212LT1G**

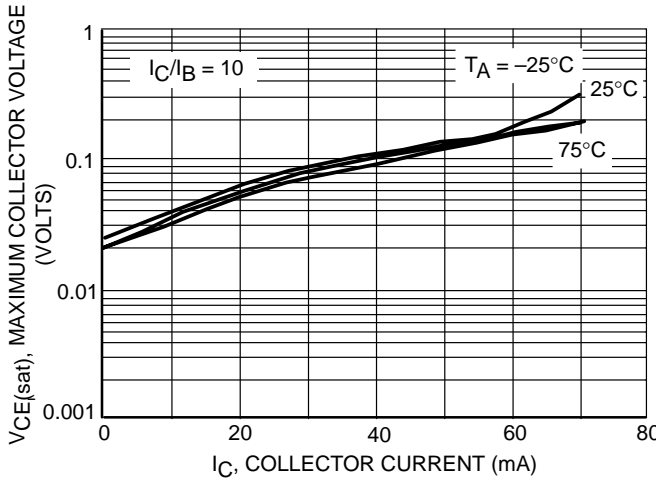


Figure 7. $V_{CE(sat)}$ vs. I_C

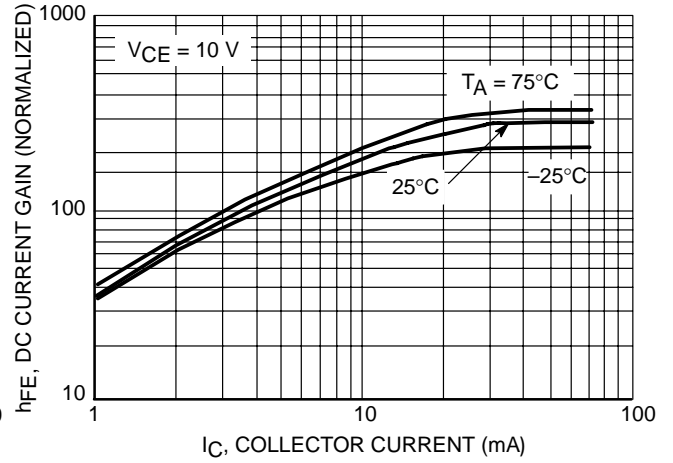


Figure 8. DC Current Gain

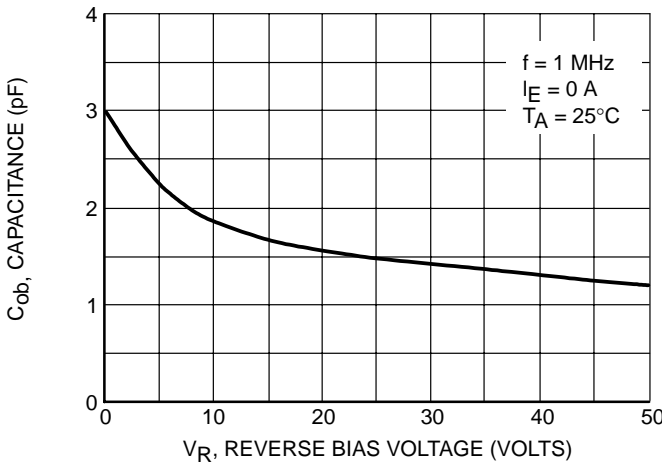


Figure 9. Output Capacitance

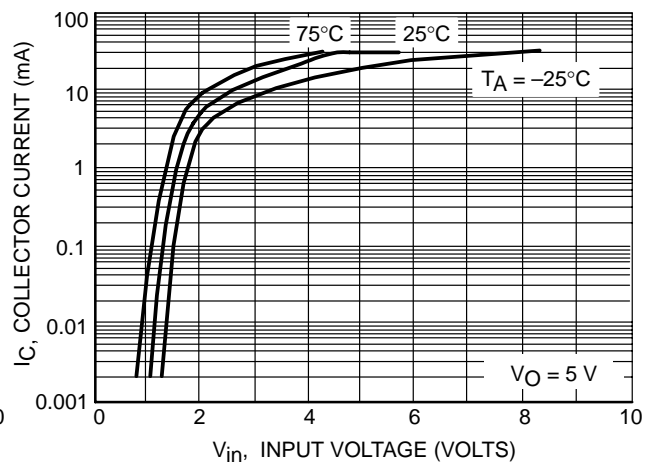


Figure 10. Output Current vs. Input Voltage

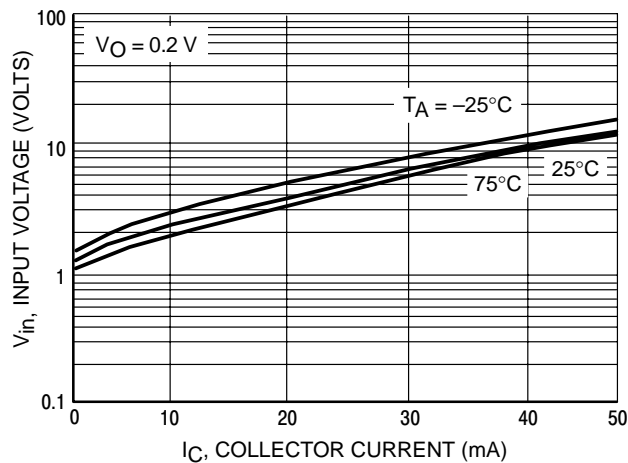


Figure 11. Input Voltage vs. Output Current

TYPICAL ELECTRICAL CHARACTERISTICS
MUN2213LT1G

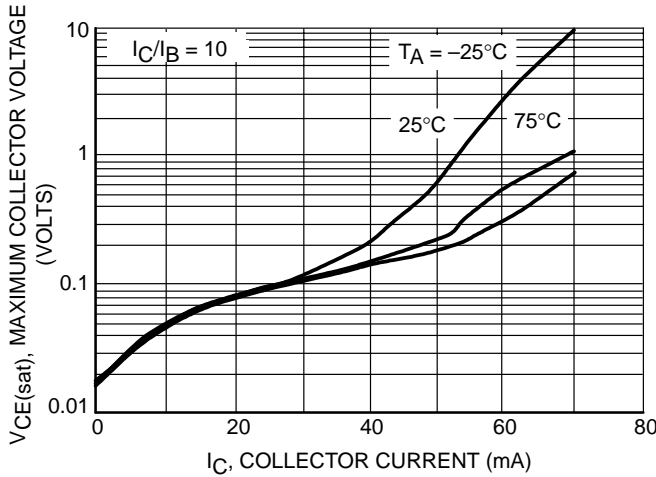


Figure 12. VCE(sat) vs. IC

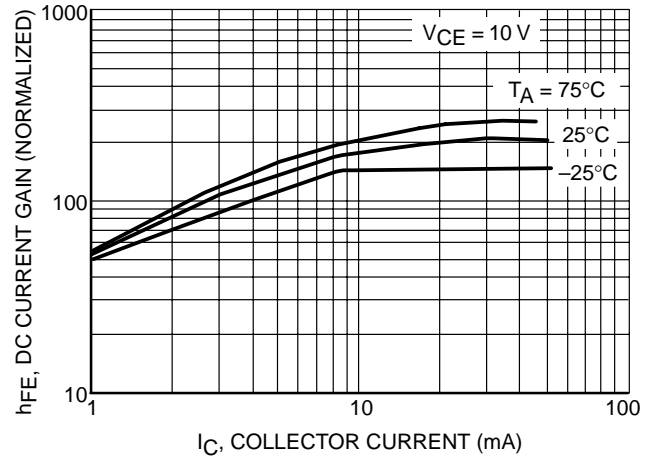


Figure 13. DC Current Gain

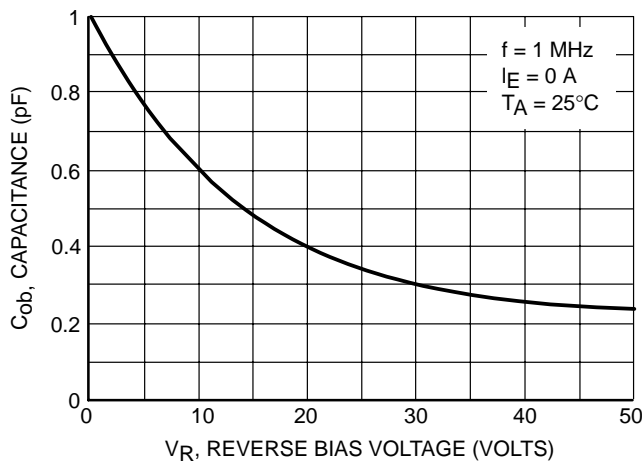


Figure 14. Output Capacitance

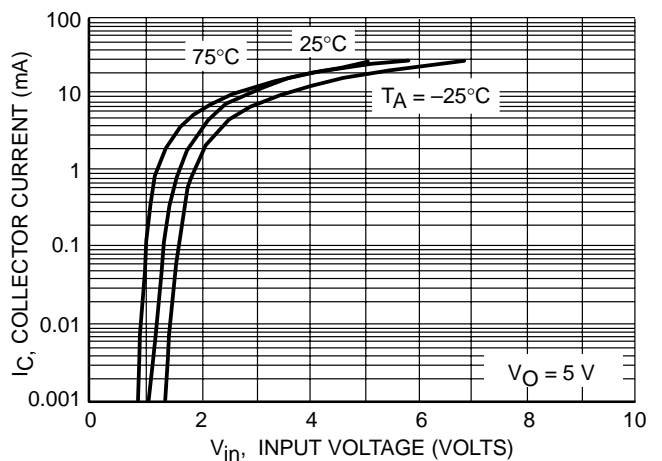


Figure 15. Output Current vs. Input Voltage

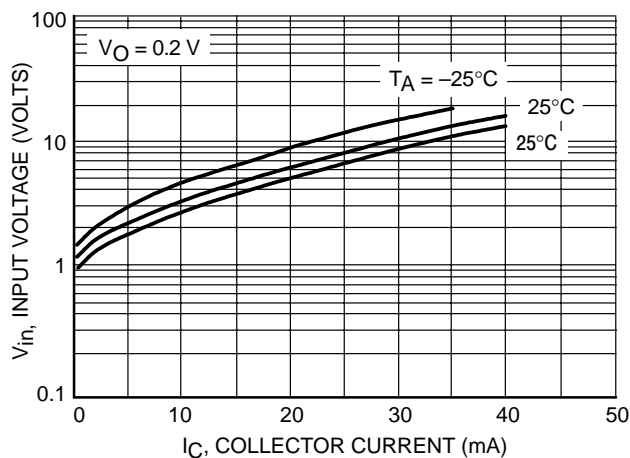


Figure 16. Input Voltage vs. Output Current

**TYPICAL ELECTRICAL CHARACTERISTICS
 MUN2214LT1G**

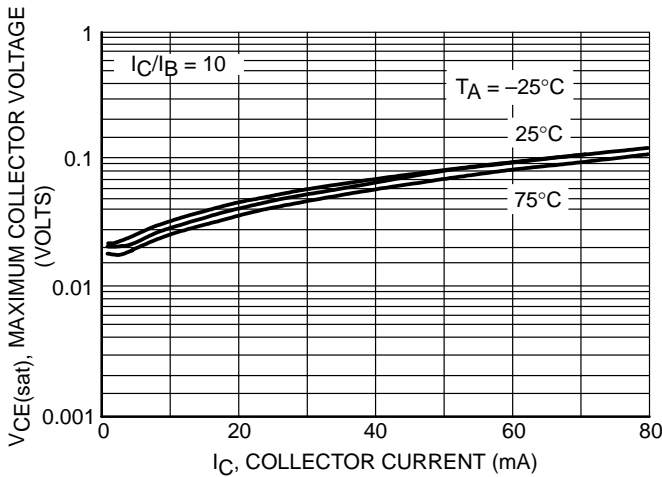


Figure 17. VCE(sat) vs. IC

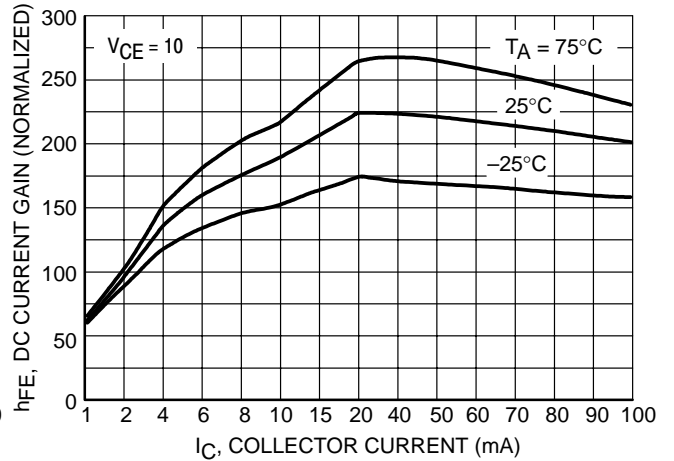


Figure 18. DC Current Gain

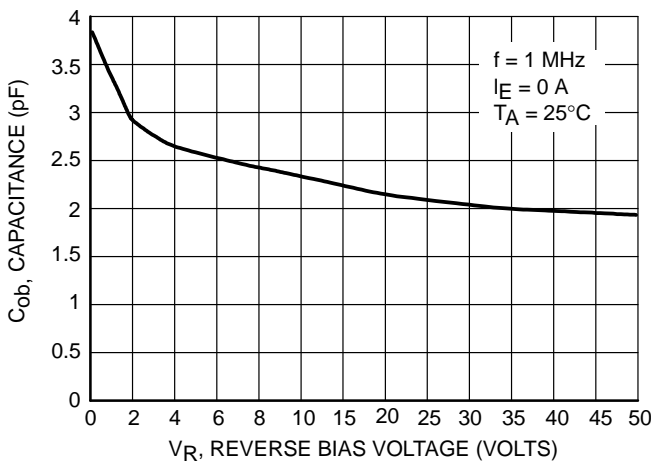


Figure 19. Output Capacitance

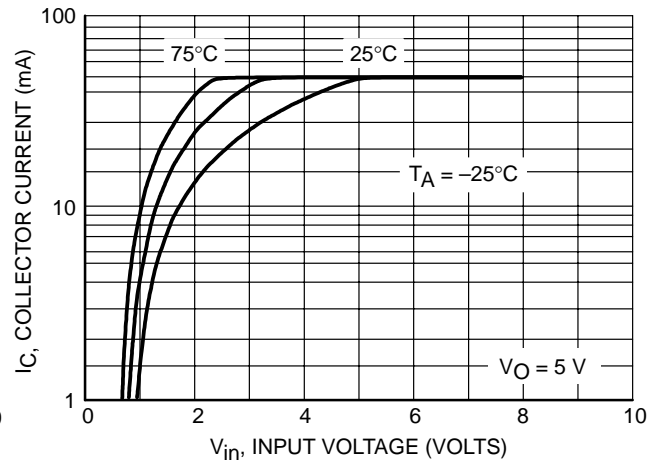


Figure 20. Output Current vs. Input Voltage

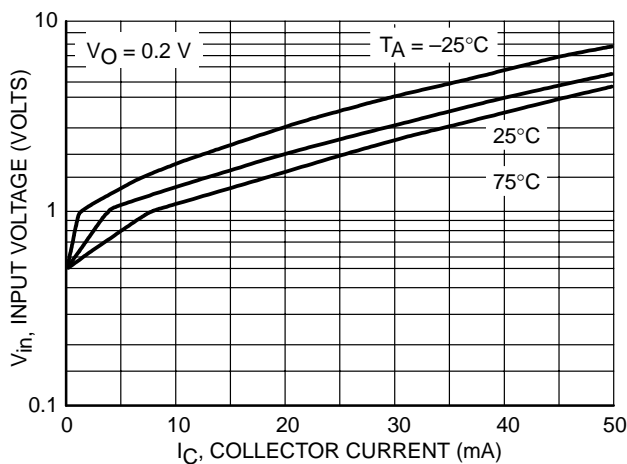


Figure 21. Input Voltage vs. Output Current

TYPICAL ELECTRICAL CHARACTERISTICS
MUN2215LT1G

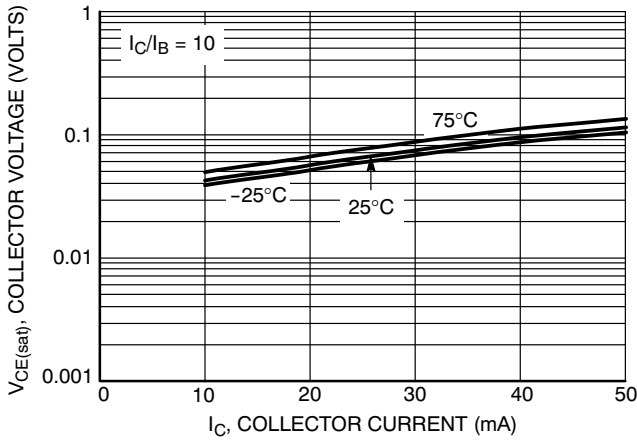


Figure 22. $V_{CE(sat)}$ versus I_C

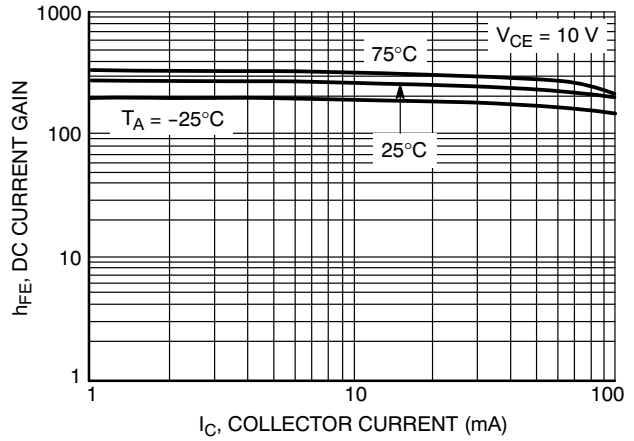


Figure 23. DC Current Gain

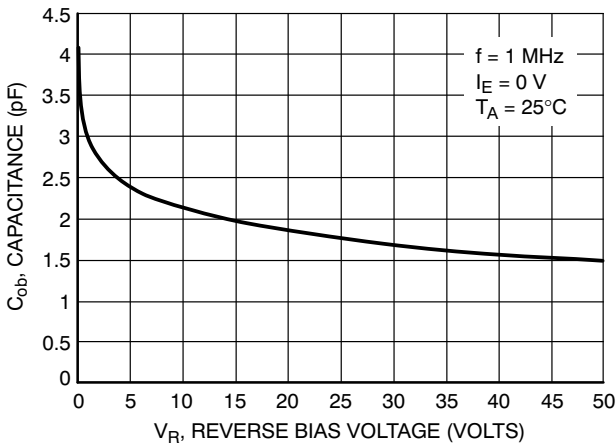


Figure 24. Output Capacitance

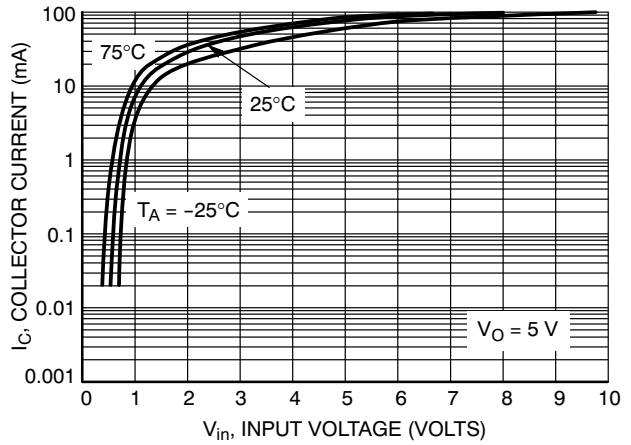


Figure 25. Output Current versus Input Voltage

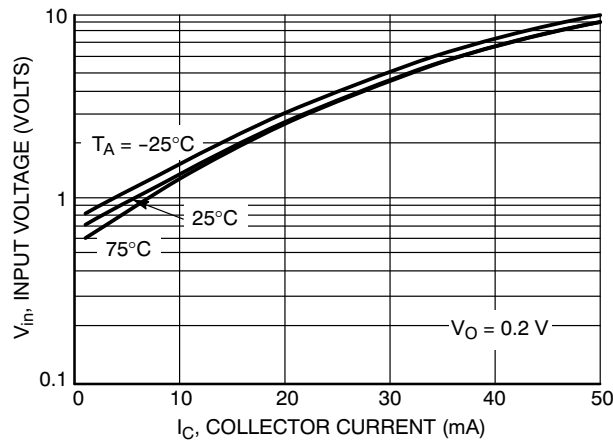


Figure 26. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS
MUN2216LT1G

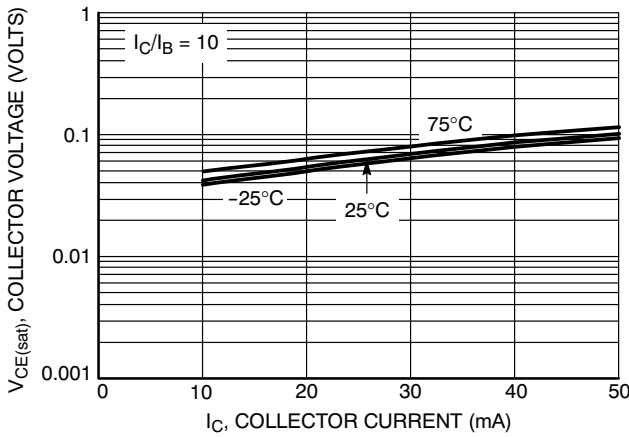


Figure 27. $V_{CE(sat)}$ versus I_C

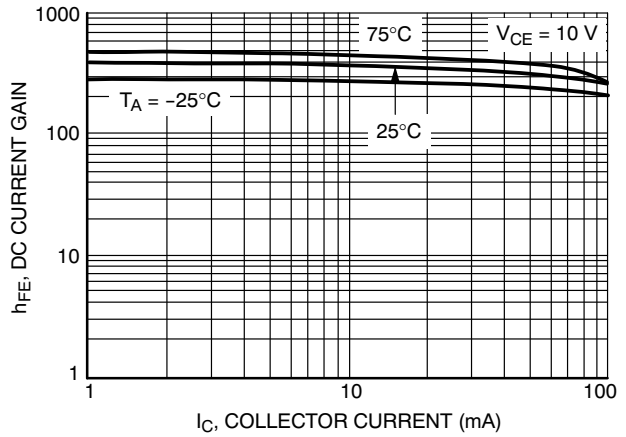


Figure 28. DC Current Gain

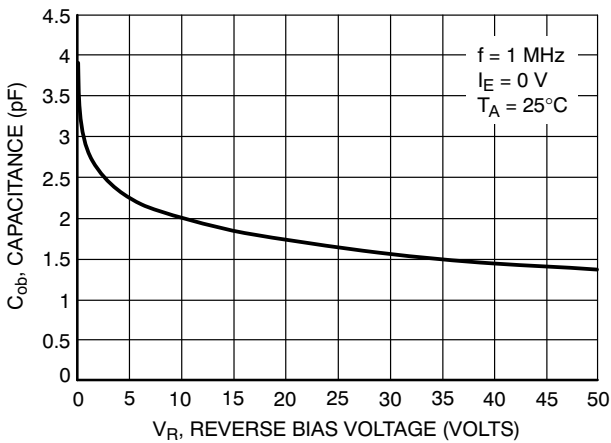


Figure 29. Output Capacitance

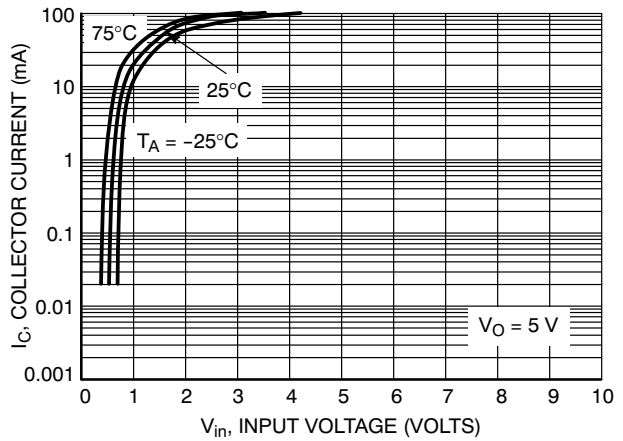


Figure 30. Output Current versus Input Voltage

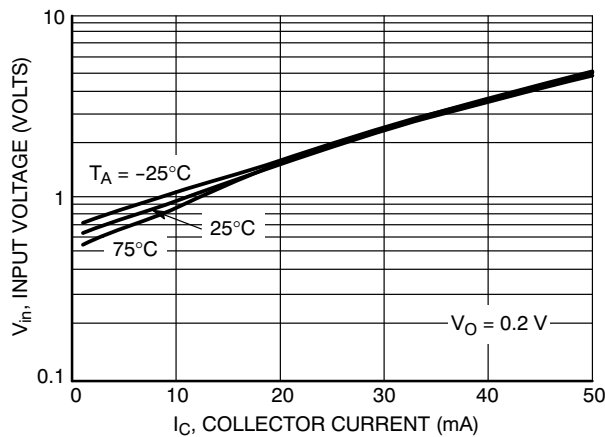


Figure 31. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS
MUN2230LT1G

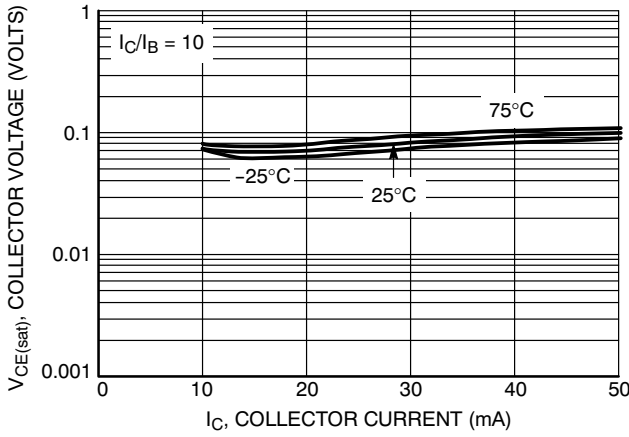


Figure 32. $V_{CE(sat)}$ versus I_C

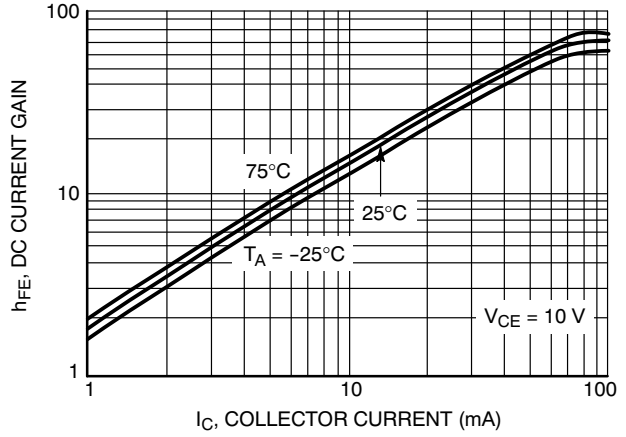


Figure 33. DC Current Gain

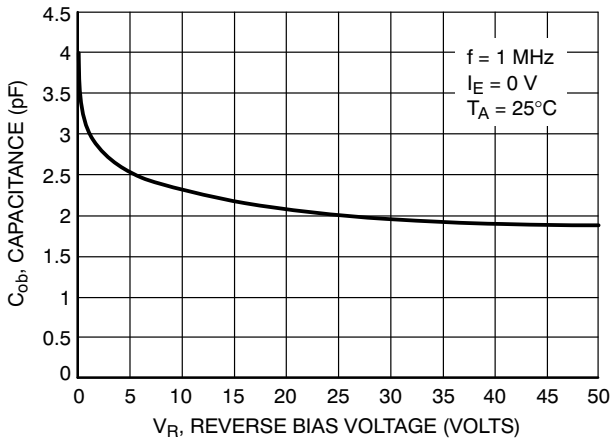


Figure 34. Output Capacitance

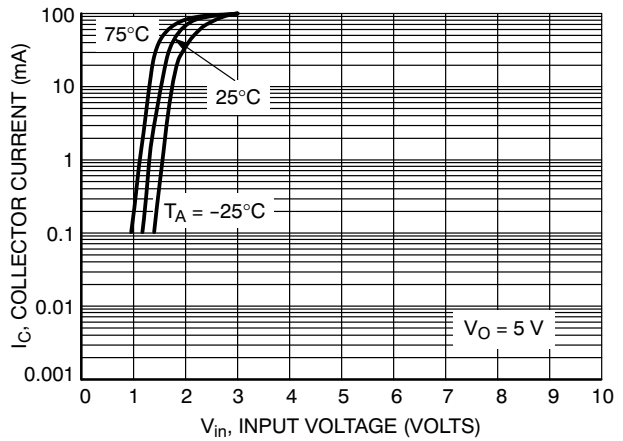


Figure 35. Output Current versus Input Voltage

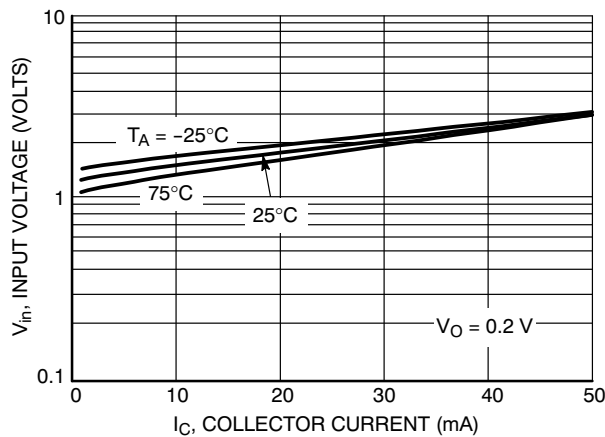


Figure 36. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS
MUN2231LT1G

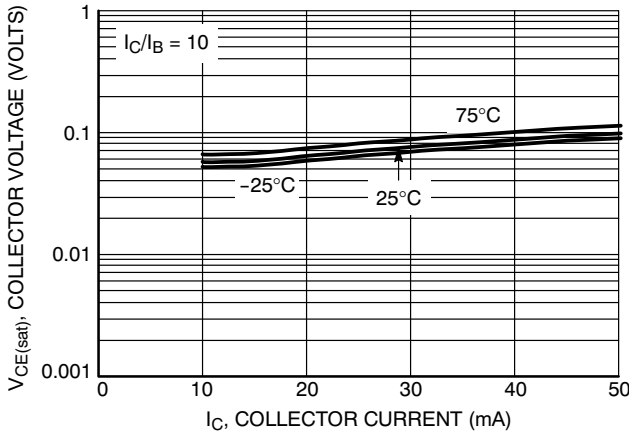


Figure 37. $V_{CE(sat)}$ versus I_C

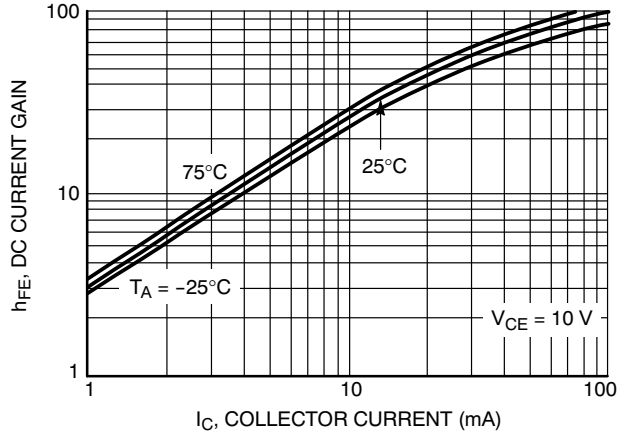


Figure 38. DC Current Gain

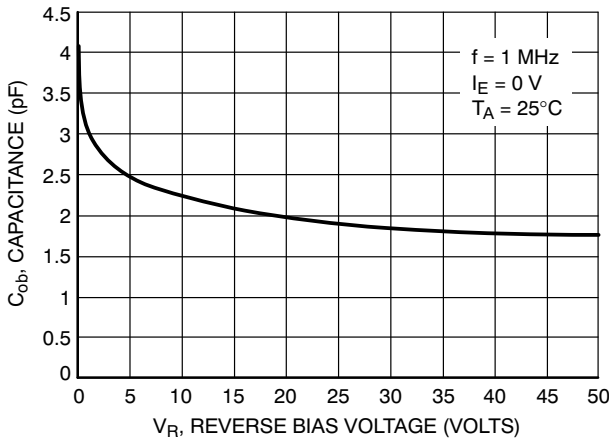


Figure 39. Output Capacitance

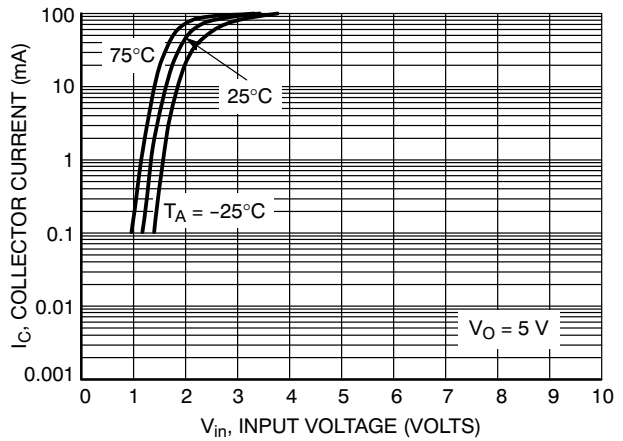


Figure 40. Output Current versus Input Voltage

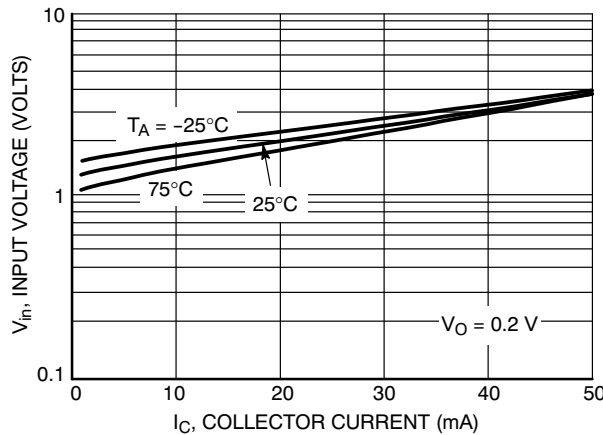


Figure 41. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS
MUN2232LT1G

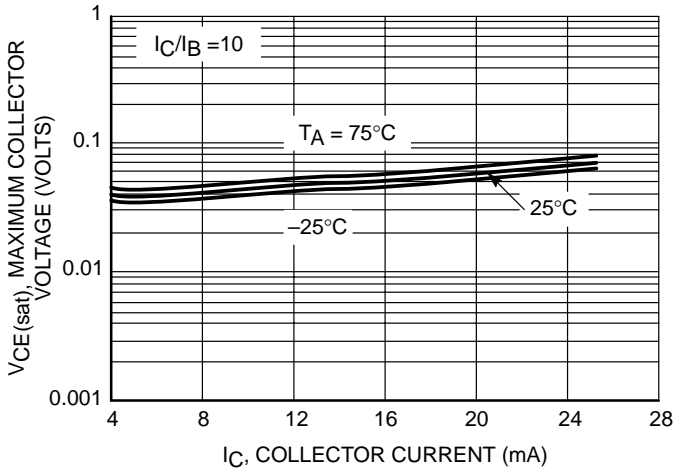


Figure 22. $V_{CE(sat)}$ vs. I_C

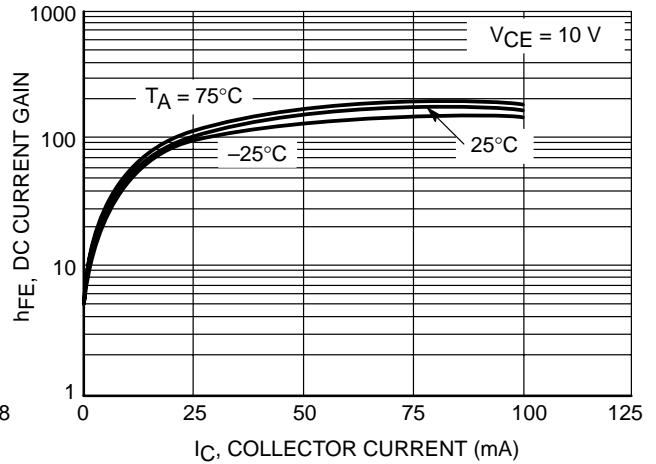


Figure 23. DC Current Gain

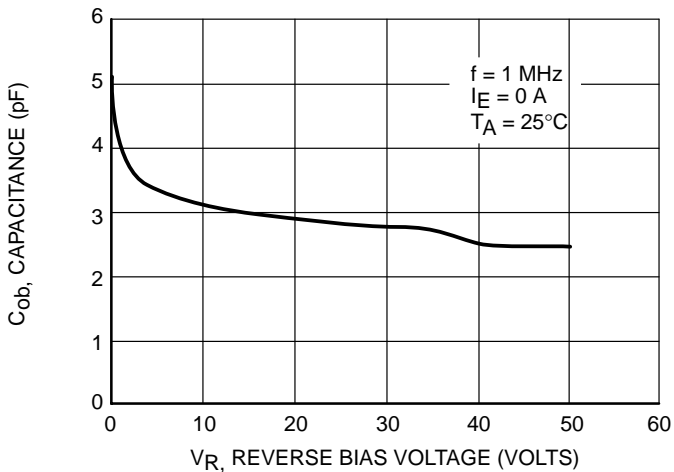


Figure 24. Output Capacitance

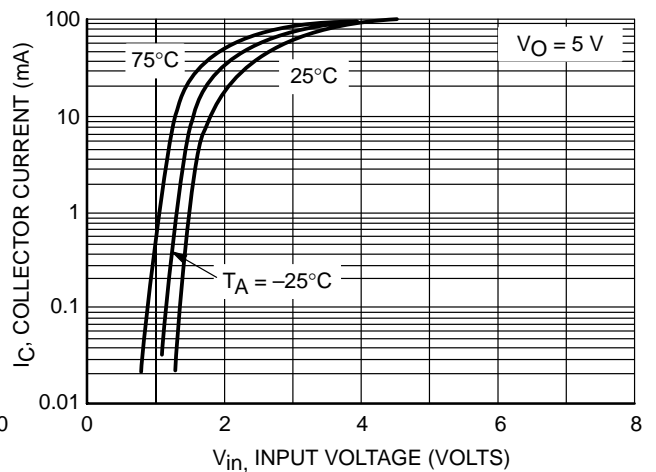


Figure 25. Output Current vs. Input Voltage

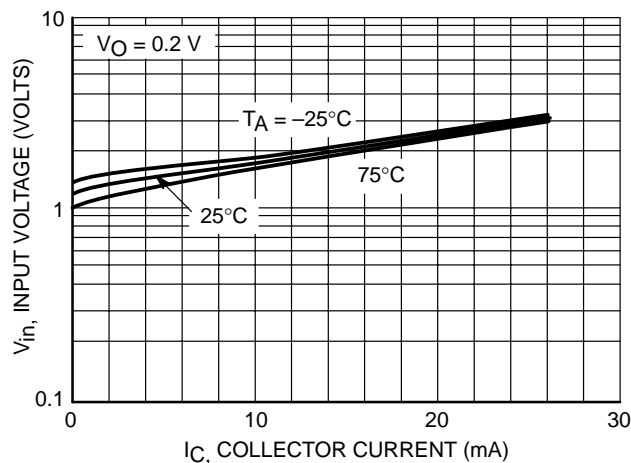


Figure 26. Output Voltage vs. Input Current

TYPICAL ELECTRICAL CHARACTERISTICS
MUN2233LT1G

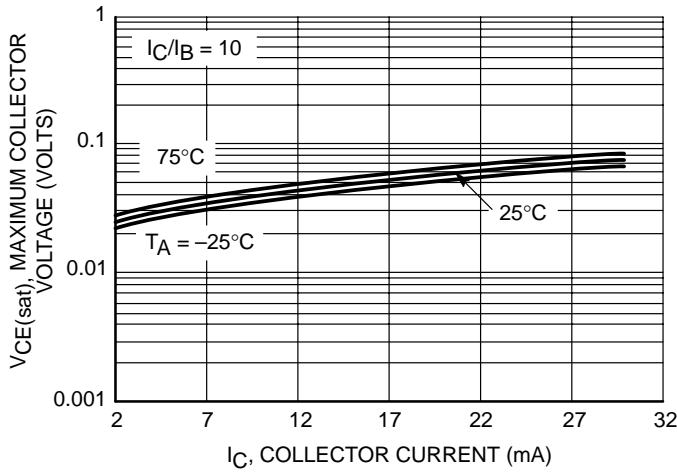


Figure 27. VCE(sat) vs. IC

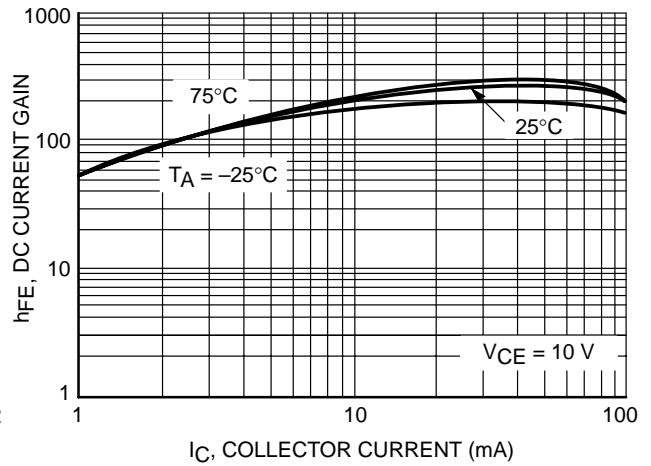


Figure 28. DC Current Gain

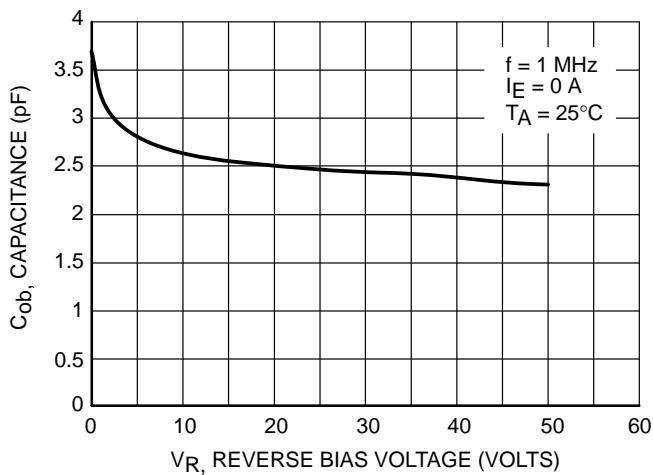


Figure 29. Output Capacitance

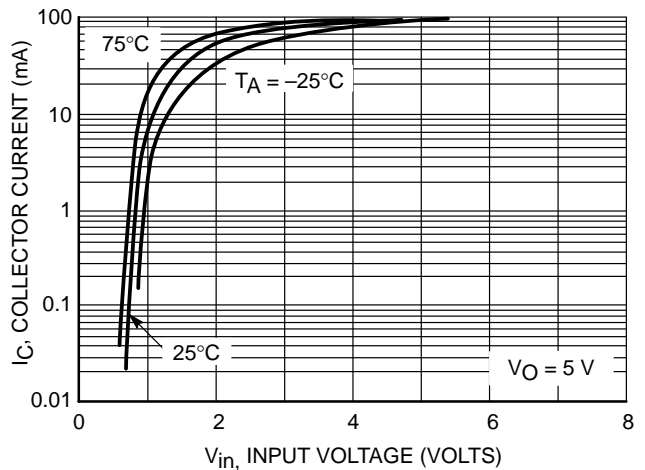


Figure 30. Output Current vs. Input Voltage

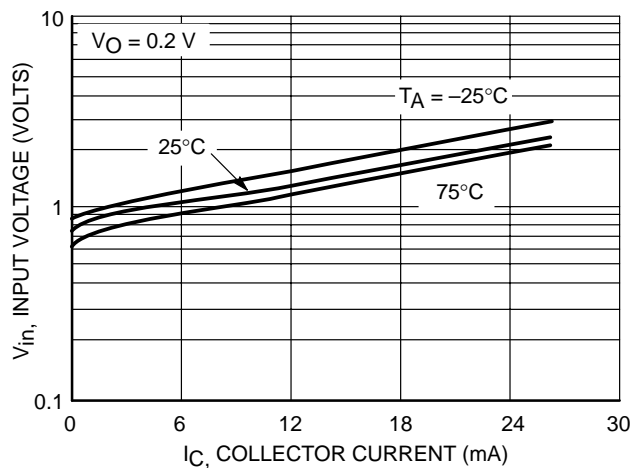


Figure 31. Input Voltage vs. Output Current

TYPICAL ELECTRICAL CHARACTERISTICS
MUN2234LT1G

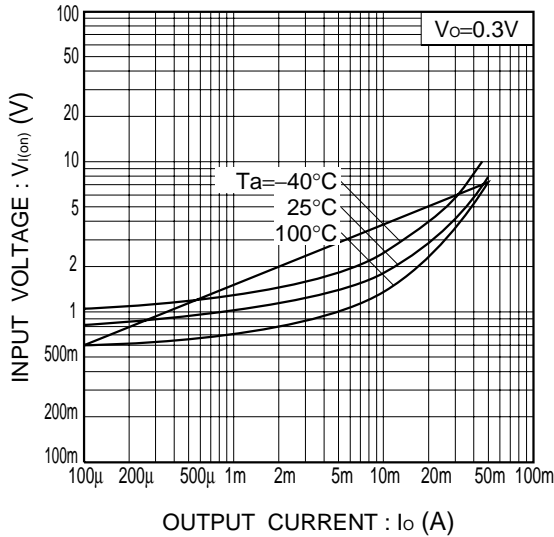


Fig.1 Input voltage vs. output current (ON characteristics)

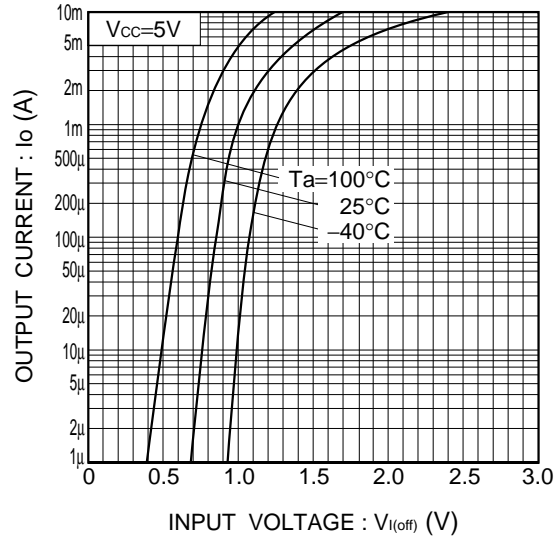


Fig.2 Output current vs. input voltage (OFF characteristics)

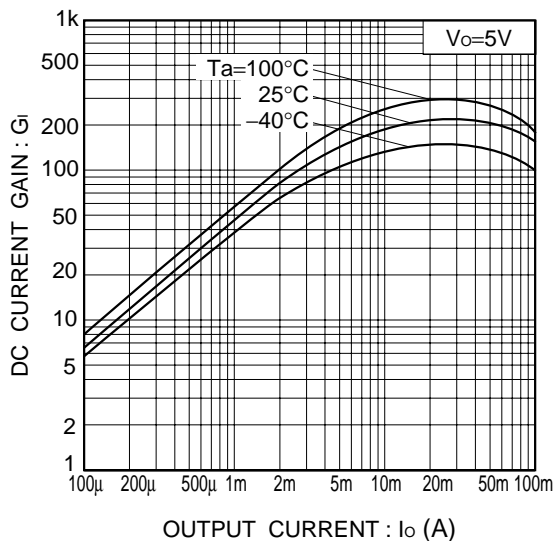


Fig.3 DC current gain vs. output current

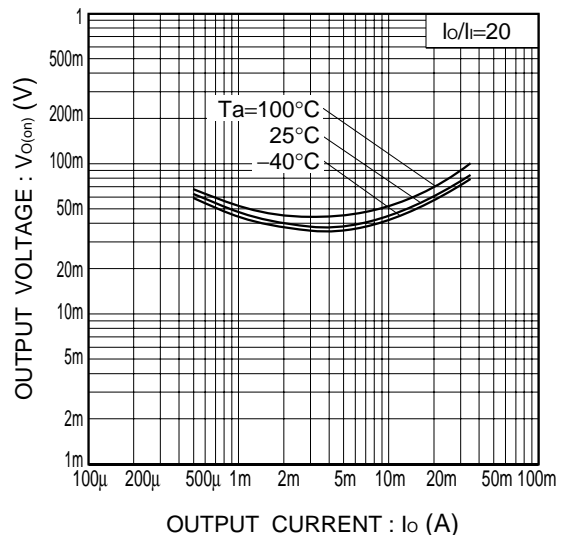


Fig.4 Output voltage vs. output current

TYPICAL APPLICATIONS FOR NPN BRTs

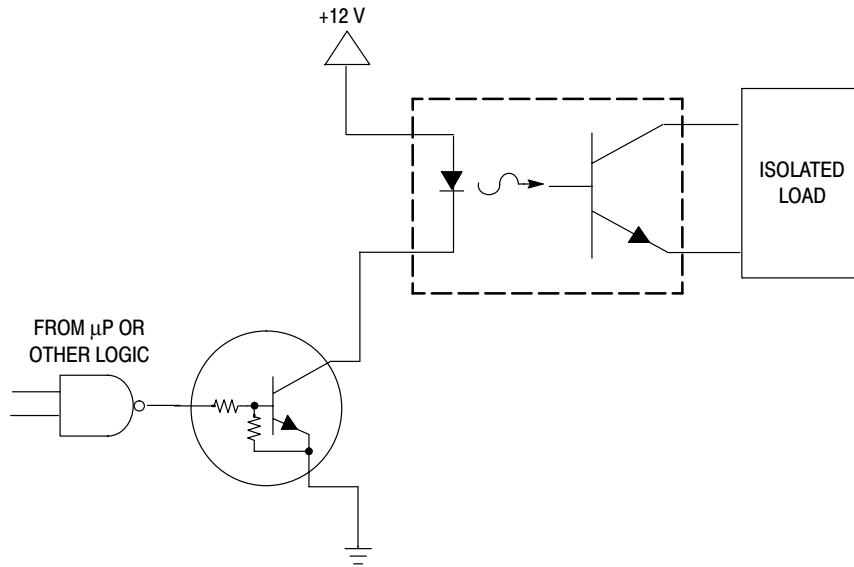


Figure 32. Level Shifter: Connects 12 or 24 Volt Circuits to Logic

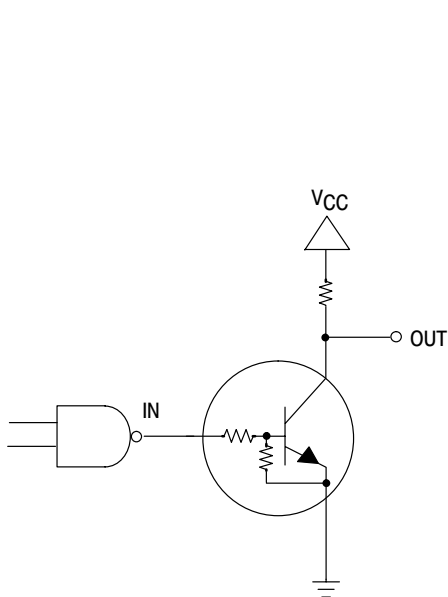


Figure 33. Open Collector Inverter: Inverts the Input Signal

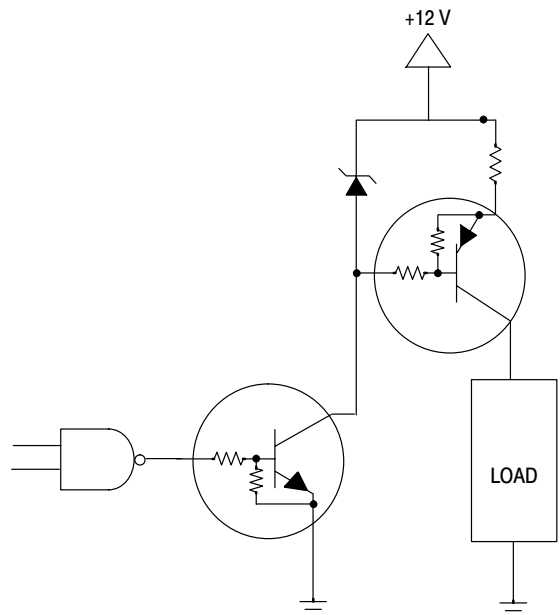
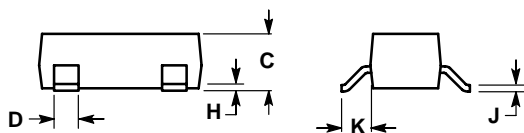
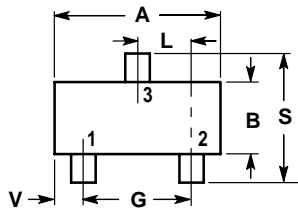


Figure 34. Inexpensive, Unregulated Current Source

SOT-23



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

